

PESD18VF1BL

Ultra low capacitance bidirectional ESD protection diode Rev. 1— 2 September 2013 Product data

Product data sheet

1. **General description**

Ultra low capacitance bidirectional ElectroStatic Discharge (ESD) protection diode in a DFN1006-2 (SOD882) leadless ultra small Surface-Mounted Device (SMD) plastic package designed to protect one signal line from the damage caused by ESD and other transients.

2. **Features and benefits**

- Ultra low diode capacitance C_d = 0.35 pF
- High reverse standoff voltage V_{RWM} = 18 V
- Very small voltage dependency of the capacitance
- ESD protection up to ±10 kV according to IEC 61000-4-2, level 4

Applications 3.

- NFC antenna protection
- · Protection of high-speed data lines

Quick reference data 4.

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
C_{d}	diode capacitance	$f = 1 MHz; V_R = 0 V$	0.28	0.35	0.5	pF
V_{RWM}	reverse standoff voltage		-	-	18	V

Pinning information

Table 2. **Pinning information**

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	K1	cathode (diode 1)		
2	K2	cathode (diode 2)	1 2	1 2 sym045
			Transparent top view	
			DFN1006-2 (SOD882)	



6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PESD18VF1BL	DFN1006-2	leadless ultra small plastic package; 2 terminals	SOD882

7. Marking

Table 4. Marking codes

Type number	Marking code
PESD18VF1BL	WM

8. Limiting values

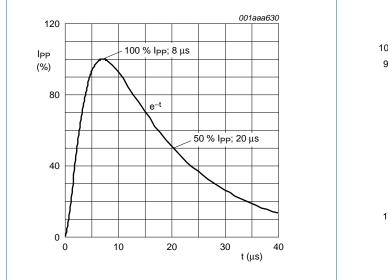
Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
I _{PPM}	peak pulse current	t _p = 8/20 μs; IEC 61000-4-5; IEC 61643-321	<u>[1]</u>	-	1	Α
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-55	150	°C
T _{stg}	storage temperature			-65	150	°C
ESD maxim	um ratings					
V _{ESD}	electrostatic discharge voltage	IEC 61000-4-2; contact discharge	[1][2]	-	10	kV
		IEC 61000-4-2; air discharge	[1][2]	-	15	kV
		MIL-STD-883; human body model; HBM	[1]	-	10	kV
		machine model; MM	<u>[1]</u>	-	400	V

^[1] Measured from pin 1 to pin 2.

^[2] Device stressed with ten non-repetitive ESD pulses.



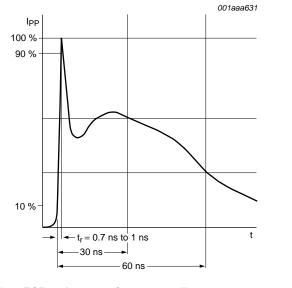


Fig 1. 8/20 μs pulse waveform according to IEC 61000-4-5 and IEC 61643-321

Fig 2. ESD pulse waveform according to IEC 61000-4-2

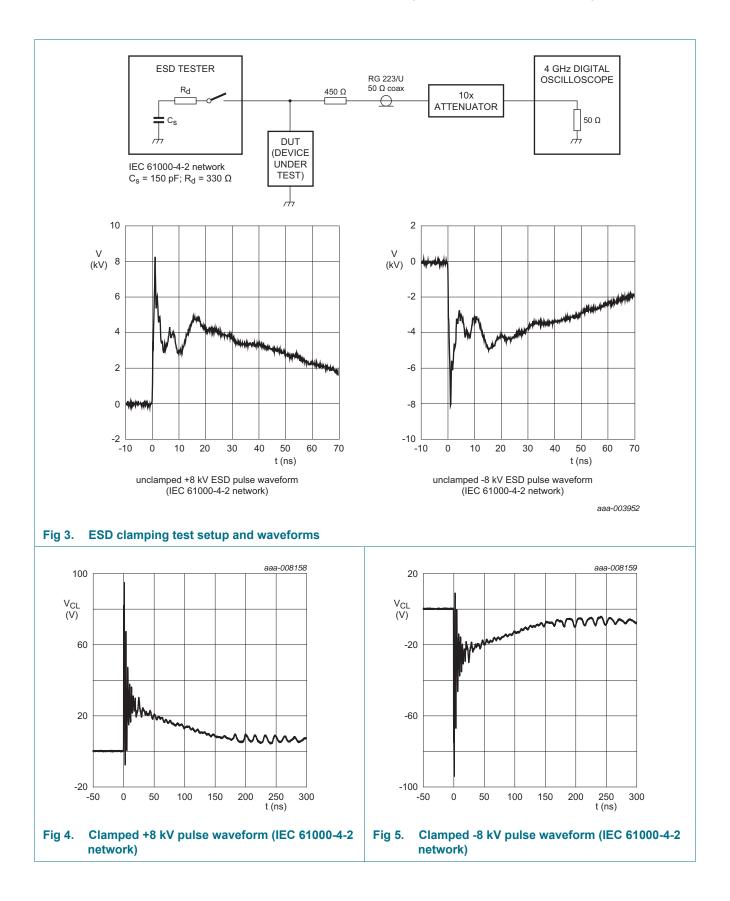
9. Characteristics

Table 6. Characteristics

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Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V_{RWM}	reverse standoff voltage			-	-	18	V
I _{RM}	reverse leakage current	V _R = 18 V		-	1	30	nA
V_{CL}	clamping voltage	I_{PP} = 1 A; t_p = 8/20 µs; IEC 61000-4-5; IEC 61643-321	<u>[1]</u>	-	-	17	V
V_{BR}	breakdown voltage	I _R = 10 mA		19	22	24	V
C_d	diode capacitance	$f = 1 MHz; V_R = 0 V$		0.28	0.35	0.5	pF
R _{dyn}	dynamic resistance	I _R = 10 A	[2]	-	0.8	-	Ω

^[1] Measured from pin 1 to pin 2.

[2] Non-repetitive current pulse, Transmission Line Pulse (TLP) tp = 100 ns; square pulse; ANSI / ESD STM5.1-2008.



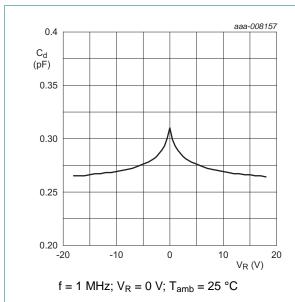


Fig 6. Diode capacitance as a function of reverse voltage; typical values

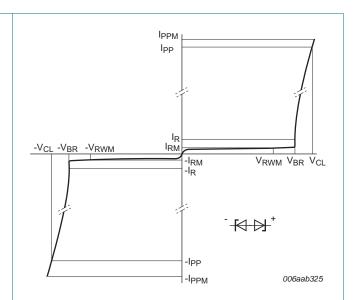
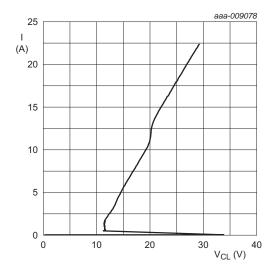


Fig 7. V-I characteristics for a bidirectional ESD protection diode

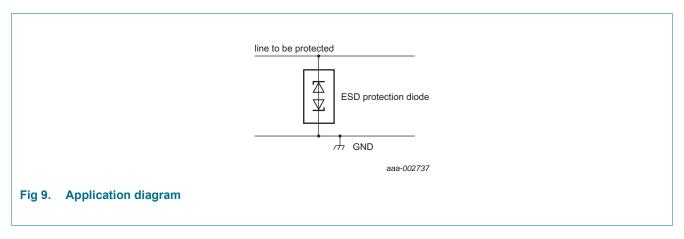


 t_p = 100 ns; Transmission Line Pulse (TLP)

Fig 8. Dynamic resistance

10. Application information

The device is designed for the protection of one bidirectional data line from surge pulses and ESD damage. The device is suitable on lines where the signal polarities are both positive and negative with respect to ground.

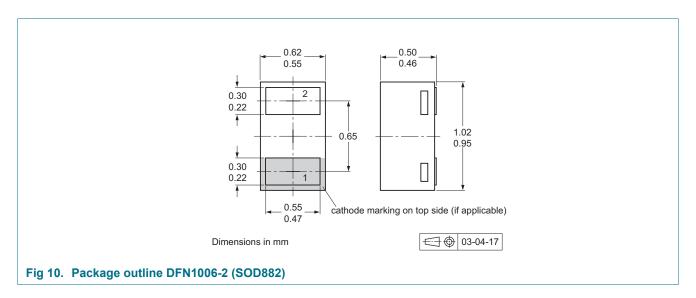


Circuit board layout and protection device placement

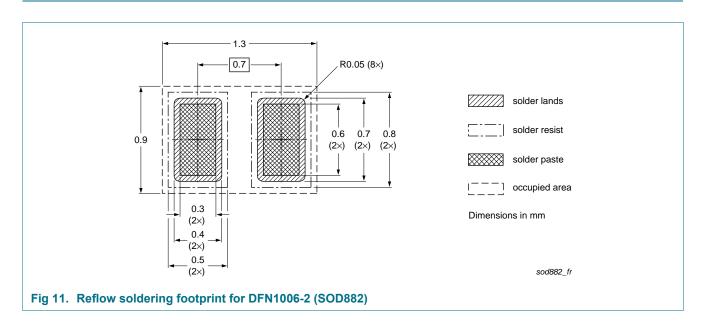
Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

- 1. Place the device as close to the input terminal or connector as possible.
- 2. Minimize the path length between the device and the protected line.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- Use ground planes whenever possible. For multilayer PCBs, use ground vias.

11. Package outline



12. Soldering





13. Revision history

Table 7. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PESD18VF1BL v.1	20130902	Product data sheet	-	-

14. Legal information

14.1 Data sheet status

Document status[1] [2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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